



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Masahiro Tanaka

Atty. Docket No. 075834.00067

Serial No.: 09/ 834,075

Group Art Unit: 2811

Filed: April 12, 2001

Examiner: Cuong Quang Nguyen

Invention: " NONVOLATILE SEMICONDUCTOR STORAGE DEVICE"

AMENDMENT A

Assistant Commissioner of Patents  
Washington, D.C. 20231

S I R:

In response to the Office Action dated December 23, 2002, please amend the application as follows:

PETITION FOR EXTENSION OF TIME

Applicant hereby petitions for a one-month extension of time to respond to the outstanding Office Action under 37 C.F.R. §1.136(a). The time to respond is thus extended to April 23, 2003. Applicant has included a check in the amount of \$110.00 as payment of the required fee set forth in 37 C.F.R. §1.17(a).

IN THE CLAIMS:

1. (Once Amended) A nonvolatile semiconductor storage device provided with a capacitor using a ferroelectric thin film, wherein:

the ferroelectric thin film is comprised of a material selected from the group consisting of:

LiNbO<sub>3</sub>, La<sub>2</sub>Ti<sub>2</sub>O<sub>7</sub>, Nd<sub>2</sub>Ti<sub>2</sub>O<sub>7</sub>, Sr<sub>2</sub>Nb<sub>2</sub>O<sub>7</sub>, Bi<sub>2</sub>WO<sub>6</sub>, Bi<sub>3</sub>TiNbO<sub>9</sub> or Bi<sub>3</sub>TiTaO<sub>9</sub>.

[an apparent coercive electric field value in an operational guaranteed temperature range of said nonvolatile semiconductor storage device, when regarded as voltage applied to

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